

### SPECIFICATIONS IN BRIEF

Frequency range		
Shielding effectiveness	18 GHz to 50GHz	> 70 dB
Dimensions (W $\times$ H $\times$ D)	outside dimensions and chamber mount	1.2m×1.2m×2m
Axis		
Veight		
Door operation		manually operated
Angular resolution		
		Option > 40 GHz

Specification are subject to change without notice.



HEAD OFFICE: Shin-Yokohama KS building 7F, 3-18-3, Shin-Yokohama, Kohoku-ku, Yokohama-shi, Kanagawa, 222-0033, Japan TEL: +81-45-594-6639(main) FAX: +81-45-471-4798

www.mwf.co.jp

#### MICROWAVE FACTORY





**Plato** 

POWER DENSITY RECONSTRUCTION BY MEASUREMENTS OF ELECTRIC FIELD INTENSITY AND PHASE USING NEAR-FIELD SCANNING PROBE

## INTRODUCTION

The \$h Generation 3G PP wirelesscommunications standard, also known as 5G, will soon becomeavailable to the public. Compared to the 4h Generation 4G wireless services, 5G willoffer improvements in communications speed, reduced latency and increased capacity. Two key enabling factors of 5G are its adoption of millimeterwave frequenciesand utilization of directional phasedarray antennas.

There is growingconcern that the millimeterwave electromagnetic fields (EMF) radiated by 5G devices may have harmfuleffects, especially when concentrated or focused by phased array antennas. At lower 4G frequency bands (c10GH2) Specific Absorption Rate (SAR) measurementtechniques weretraditionally used to assess the potentially harmful effects of human exposure to wireless signals. SARtechniques are not sufficient, however, to assess applications above 10GHz becauses kin sufface heating is dominant at frequencies above 10GHz. This requires higher frequency EMF exposure techniques and standards to be adopted to address 5G millimeterwave device EMF exposure.

For SG applications, Power Density measurement techniques are being adopted to assess the safety of wireless signal levels for applications greater than 10GHz and to ensure conformance to EMF exposure limits. The Plato platform offered by Microwave Factory is a turn key Power Density measurementsy stem forevaluating EMF exposure at SG millimeter wave bands.



# **RECONSTRUCTION ALGORITHM**

Measure Ex and Ey Fiel ds on Measurement Plane z1

E-fiel ds on theevaluation plane z0 are reconstructed

H-fields on the evaluation plane z0 derive d using reconstructed E-fiel ds

Extended capability of Phaseless Measurementsfor power density evaluation

Power density evaluated from E and H fields at evaluation plane z0

Thereare several method to evaluate power density of wireless devices. One of the evaluation method is based upon the evaluation flectric Filed (E-field) and Magnetic Field (H-field). Another method is based on planewave equivalent approximation. For power density based on E- and H- fields, the near E- and near H- fields are measured on a surface and the their Poy inting vector evaluate d. Fig.1 shows schematic view of power density assessment in close proximity to a device using this technique.



Fig.1 Schematic of power density reconstructed side view

> Fig.2 Reconstructed Power Density from Near Field measurements Reference Horn antennaat 30 GH z z0 = 2mm



### SOFTWARE

Plato is designed an d develope d a power density measurement system. This system is use d forevaluation of the power density at millimeter wavefrequency for wireless devise. Thus, Plato is able to confirmcomplianceto RF-EMC exposurestan dardsfor wireless devices usingthis system.

Plato software automatically calculates and displays power density values according to a reconstruction algorithm based on data acquired from the instrument. The user determines the range of measurement and the Platosoftware automatically measures the maximum power density.



Product image for illustration purposes only. Actual product may vary.